





SBVS049D - MAY 2004 - REVISED AUGUST 2010

Dual 250 mA Output, UltraLow Noise, High PSRR, Low-Dropout Linear Regulator

Check for Samples: TPS71202, TPS71219, TPS71229, TPS71247, TPS71256, TPS71257

FEATURES

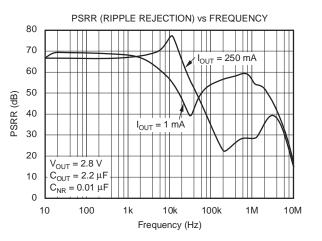
- Dual 250 mA High-Performance RF LDOs
- Available in Fixed and Adjustable Voltage Options (1.2 V to 5.5 V)
- High PSRR: 65 dB at 10 kHz
- UltraLow Noise: 32 µVrms
- Fast Start-Up Time: 60 μs
- Stable with 2.2 µF Ceramic Capacitor
- Excellent Load/Line Transient Response
- Very Low Dropout Voltage: 125 mV at 250 mA
- Independent Enable Pins
- Thermal Shutdown and Independent Current Limit
- Available in Thermally-Enhanced SON Package: 3mm x 3mm x 1mm

APPLICATIONS

- Cellular and Cordless Phones
- Wireless PDA/Handheld Products
- PCMCIA/Wireless LAN Applications
- Digital Camera/Camcorder/Internet Audio
- DSP/FPGA/ASIC/Controllers and Processors

DESCRIPTION

The TPS712xx family of low-dropout (LDO) voltage regulators is tailored to noise-sensitive and RF applications. These products feature dual 250 mA LDOs with ultralow noise, high power-supply rejection ratio (PSRR), and fast transient and start-up response. Each regulator output is stable with low-cost 2.2 µF ceramic output capacitors and features very low dropout voltages (125 mV typical at 250 mA). Each regulator achieves fast start-up times (approximately 60 µs with a 0.001 µF bypass capacitor) while consuming very low quiescent current (300 µA typical with both outputs enabled). When the device is placed in standby mode, the supply current is reduced to less than 0.3 µA typical. Each regulator exhibits approximately 32 µVrms of output voltage noise with V_{OUT} = 2.8 V and a 0.01 μ F noise reduction (NR) capacitor. Applications with analog components that are noise-sensitive, such as portable RF electronics, will benefit from high PSRR, low noise, and fast line and load transient features. The TPS712 family is offered in a thin 3mm x 3mm SON package and is fully specified from -40°C to +125°C (T_J).



DRC PACKAGE 3mm x 3mm SON (TOP VIEW) 10 IN 11 EN1 NC FB1/NC 9 2 OUT1 3 EN2 8 OUT2 4 7 FB2/NC GND 51 6 NR

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TPS71202, TPS71219 TPS71229, TPS71247 TPS71256, TPS71257 SBVS049D - MAY 2004 - REVISED AUGUST 2010



www.ti.com



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ODDEDING INFORMATION(1)

ORDERING INFORMATION **										
	VOLTA	GE (V)	PACKAGE-	SPECIFIED						
PRODUCT	V _{OUT1}	V _{OUT2}	LEAD (DESIGNATOR)	TEMPERATURE RANGE (T _J)	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY			
TD074000	Adjustable	Adjustable		10°C to 1125°C		TPS71202DRCT	Tape and Reel, 250			
TPS71202	Adjustable	Adjustable	SON-10 (DRC)	-40°C to +125°C	ARQ	TPS71202DRCR	Tape and Reel, 3000			
TD074040	1.0.1/	Adjustable		10°C to 1125°C		TPS71219DRCT	Tape and Reel, 250			
TPS71219	1.8 V	Adjustable	SON-10 (DRC)	-40°C to +125°C	ARW	TPS71219DRCR	Tape and Reel, 3000			
TPS71229	2.8 V	Adjustable	SON-10 (DRC)	-40°C to +125°C	ARU	TPS71229DRCT	Tape and Reel, 250			
19571229	2.0 V	Adjustable	50N-10 (DRC)	-40°C 10 +125°C	ARU	TPS71229DRCR	Tape and Reel, 3000			
TD074047	4.0.1/	0.05.1/		10°C to 1105°C	4.0.0	TPS71247DRCT	Tape and Reel, 250			
TPS71247	1.8 V	2.85 V	SON-10 (DRC)	-40°C to +125°C	ARS	TPS71247DRCR	Tape and Reel, 3000			
TD074050	2.0.1/	0.0.1/		10°C to 1105°C		TPS71256DRCT	Tape and Reel, 250			
TPS71256	2.8 V	2.8 V	SON-10 (DRC)	-40°C to +125°C	ARV	TPS71256DRCR	Tape and Reel, 3000			
TD074057		0.05.1/		10°C to 1105°C	ADT	TPS71257DRCT	Tape and Reel, 250			
TPS71257	2.85 V	2.85 V	SON-10 (DRC)	-40°C to +125°C	ART	TPS71257DRCR	Tape and Reel, 3000			

(1) For the most current package and ordering information, see the Package Ordering Addendum located at the end of this data sheet.

ABSOLUTE MAXIMUM RATINGS

over operating junction temperature range unless otherwise noted⁽¹⁾

	TPS712xx	UNIT			
V _{IN} range	-0.3 to 6.0	V			
V _{EN1} , V _{EN2} range	-0.3 to V _{IN} + 0.3	V			
V _{OUT} range	-0.3 to 6.0	V			
Peak output current	Internally limited				
Output short-circuit duration	Indefinite				
Continuous total power dissipation	See Dissipation Ratings Table				
Junction temperature range, T _J	-40 to +150	°C			
Storage temperature range	-65 to +150	°C			
ESD rating, HBM	2	kV			
ESD rating, CDM	500	V			

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under the Electrical Characteristics is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

THERMAL INFORMATION

	THERMAL METRIC ⁽¹⁾⁽²⁾	TPS712xx	
		DRC (10 PINS)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	49.6	
θ_{JCtop}	Junction-to-case (top) thermal resistance	70.0	
θ_{JB}	Junction-to-board thermal resistance	17.8	°C/M
ΨJT	Junction-to-top characterization parameter	0.6	°C/W
Ψјв	Junction-to-board characterization parameter	15.2	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	5.2	

For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
 For thermal estimates of this device based on PCB copper area, see the TI PCB Thermal Calculator.

2 Submit Documentation Feedback

Product Folder Link(s): TPS71202 TPS71219 TPS71229 TPS71247 TPS71256 TPS71257



www.ti.com

ELECTRICAL CHARACTERISTICS

Over operating temperature range ($T_J = -40^{\circ}C$ to $+125^{\circ}C$), $V_{IN} =$ highest $V_{OUT(nom)} + 1.0$ V or 2.7 V (whichever is greater), $I_{OUT} = 1$ mA, $V_{EN1, 2} = 1.2$ V, $C_{OUT} = 10 \,\mu$ F, $C_{NR} = 0.01 \,\mu$ F, and adjustable LDOs are tested at $V_{OUT} = 3.0$ V, unless otherwise noted. Typical values are at $T_J = +25^{\circ}C$.

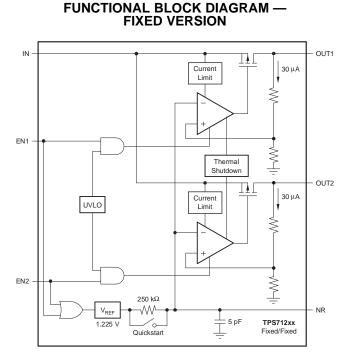
	PARAMETER		TE	MIN	TYP	MAX	UNIT			
V _{IN}	Input voltage range ⁽¹⁾				2.7		5.5	V		
V _{FB}	Internal reference (adjusta	able LDOs)			1.200	1.225	1.250	V		
	Output voltage range (adjustable LDOs)			V _{FB}	5.	5 - V _{DO}	V			
V _{OUT}		Nominal	$T_{J} = +25^{\circ}C, I_{0}$	_{DUT} = 0 mA	-1.5		+1.5			
	Accuracy ⁽¹⁾	$\begin{array}{l} \text{Over } V_{\text{IN}}, \\ I_{\text{OUT}}, \text{ and } T \end{array}$	V_{OUT} + 1.0 V ≤ V_{IN} ≤ 5.5 V, 0 µA ≤ I_{OUT} ≤ 250 mA		-3	±1	+3	%		
ΔV _{OUT} %/ΔV _{IN}	Line regulation ⁽¹⁾		V _{OUT} + 1.0 V	≤ V _{IN} ≤ 5.5 V		0.05		%/V		
ΔV _{OUT} %/ΔI _{OU} τ	Load regulation		0 μA ≤ I _{OUT} ≤	250 mA		0.8		%/mA		
V _{DO}	Dropout voltage ⁽²⁾ ($V_{IN} = V_{OUT(nom)} - 0.1V$)	2.8 V, 2.85 V Adjustable	I _{OUT1} = I _{OUT2} = 250 mA			125	230	mV		
I _{CL}	Output current limit	į	$V_{OUT} = 0.9 \times$	V _{OUT(nom)}	400	600	800	mA		
I _{GND}	Crowned min comment	One LDO enabled	I _{OUT} = 1 mA (enabled channel)			190	250	٨		
	Ground pin current	Both LDOs enabled	$I_{OUT1} = I_{OUT2}$		300	600	μΑ			
I _{SHDN}	Shutdown current ⁽³⁾		$V_{EN} \le 0.4 \text{ V}, 0.4 \text{ V}$		0.3	2.0	μA			
I _{FB}	FB pin current (adjustable	LDOs)				0.1	1	μA		
V _n	Output noise voltage,		No C_{NR} , I_{OUT} = 250 mA		80.0) × V _{OUT}		μVrms		
۷n	BW = 10 Hz - 100 kHz		C _{NR} = 0.01 μ	11.8	3 × V _{OUT}					
PSRR	Power-supply rejection ra	tio	$f = 100 \text{ Hz}, I_{C}$		65		dB			
	(ripple rejection)		$f = 10 \text{ kHz}, I_{O}$		65		UD			
t _{STR}	Startup time		V _{OUT} = 2.85 \		60		μS			
VIH	Enable threshold high (EN	N1, EN2)			1.2		V_{IN}	V		
VIL	Enable threshold low (EN1, EN2)				0		0.4	V		
I _{EN}	Enable pin current (EN1,	EN2)	$V_{IN} = V_{EN} = 5$.5 V	-1		1	μA		
т	Thormal chutdown tomas	raturo	Shutdown	+160			°C			
T _{SD}	Thermal shutdown tempe	laule	Reset	Temp decreasing		+140		- °C		
UVLO	Undervoltage lockout thre	shold	V _{IN} rising	2.25		2.65	V			
	Undervoltage lockout hys	teresis	V _{IN} falling		100		mV			

(1)

(2)

(3) For the adjustable version, this applies only after V_{IN} is applied; then V_{EN} transitions from high to low.

SBVS049D - MAY 2004 - REVISED AUGUST 2010



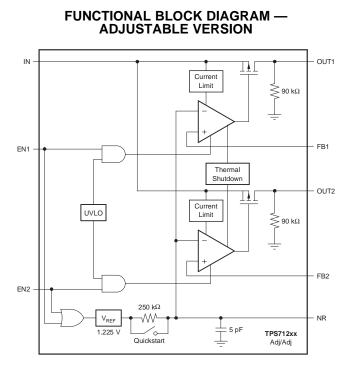


Table 1. TERMINAL FUNCTIONS

TERM	IINAL	DECODIDITION
NAME	DRC	DESCRIPTION
IN	1	Unregulated input supply. A small 0.1 μ F capacitor should be connected from IN to GND.
GND	5, Pad	Ground
OUT1	3	Output of the regulator. A small 2.2 μF ceramic capacitor is required from this pin to ground to assure stability.
OUT2	4	Same as OUT1 but for LDO2.
EN1	10	Driving the enable pin (EN) high turns on LDO1. Driving this pin low puts LDO1 into shutdown mode, reducing operating current. The enable pin should be connected to IN if not used.
EN2	8	Same as EN1 but controls LDO2.
FB1/NC	9	Feedback for CH1 adjustable version; no connection for non-adjustable CH1.
FB2/NC	7	Feedback for CH2 adjustable version; no connection for non-adjustable CH2.
NR	6	Noise reduction pin; connect an external bypass capacitor to reduce LDO output noise.
NC	2	No connection.

4

Copyright © 2004–2010, Texas Instruments Incorporated

Product Folder Link(s): TPS71202 TPS71219 TPS71229 TPS71247 TPS71256 TPS71257



www.ti.com

SBVS049D - MAY 2004 - REVISED AUGUST 2010

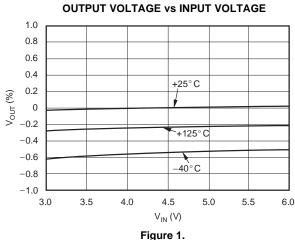
www.ti.com

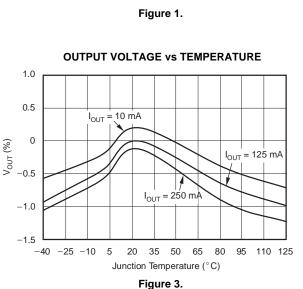
EXAS

NSTRUMENTS

TYPICAL CHARACTERISTICS

For all voltage versions at $T_J = 25^{\circ}$ C, $V_{IN} = V_{OUT(nom)} + 1$ V, $I_{OUT} = 1$ mA, $V_{EN} = 1.2$ V, $C_{OUT} = 2.2$ μ F, and $C_{NR} = 0.01$ μ F, unless otherwise noted.





OUTPUT VOLTAGE vs OUTPUT CURRENT

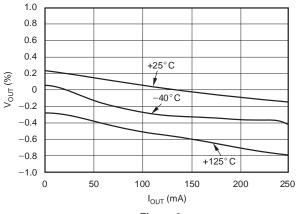
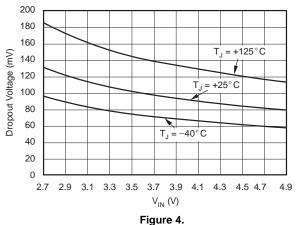
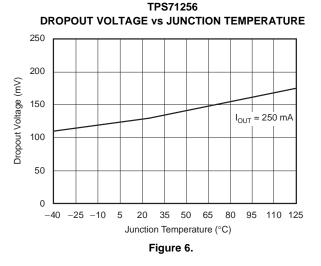


Figure 2.

DROPOUT VOLTAGE vs INPUT VOLTAGE (ADJUSTABLE VERSION)



TPS71256 DROPOUT VOLTAGE vs OUTPUT CURRENT 200 T_J = +125°C Dropout Voltage (mV) 150 100 $T_{\rm d}$ -40° C = +25°C T, 50 0 0 50 250 100 150 200 I_{OUT} (mA) Figure 5.



Copyright © 2004–2010, Texas Instruments Incorporated

Product Folder Link(s): TPS71202 TPS71219 TPS71229 TPS71247 TPS71256 TPS71257

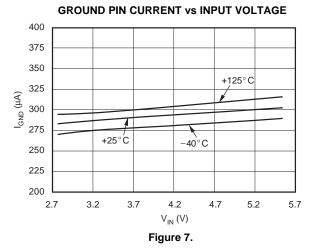
SBVS049D - MAY 2004 - REVISED AUGUST 2010

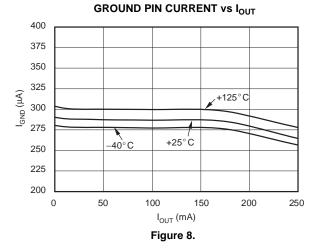


www.ti.com

TYPICAL CHARACTERISTICS (continued)

For all voltage versions at $T_J = 25^{\circ}$ C, $V_{IN} = V_{OUT(nom)} + 1$ V, $I_{OUT} = 1$ mA, $V_{EN} = 1.2$ V, $C_{OUT} = 2.2$ μ F, and $C_{NR} = 0.01$ μ F, unless otherwise noted.





GROUND PIN CURRENT vs JUNCTION TEMPERATURE

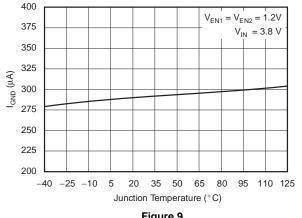
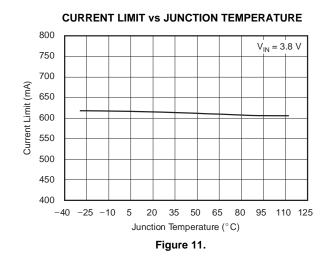
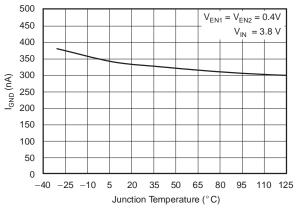


Figure 9.



GROUND PIN CURRENT vs JUNCTION TEMPERATURE (DISABLED)





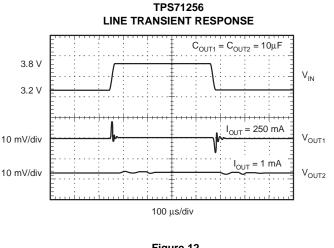


Figure 12.

Submit Documentation Feedback

Product Folder Link(s): TPS71202 TPS71219 TPS71229 TPS71247 TPS71256 TPS71257



TPS71202, TPS71219 TPS71229, TPS71247 TPS71256, TPS71257 SBVS049D - MAY 2004 - REVISED AUGUST 2010

www.ti.com

TYPICAL CHARACTERISTICS (continued)

For all voltage versions at $T_J = 25^{\circ}C$, $V_{IN} = V_{OUT(nom)} + 1$ V, $I_{OUT} = 1$ mA, $V_{EN} = 1.2$ V, $C_{OUT} = 2.2$ μ F, and $C_{NR} = 0.01$ μ F, unless otherwise noted.

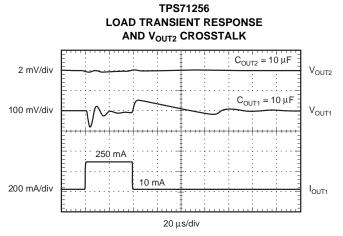
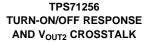
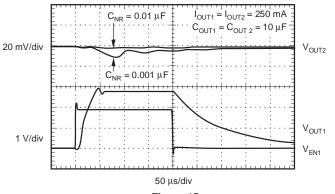


Figure 13.



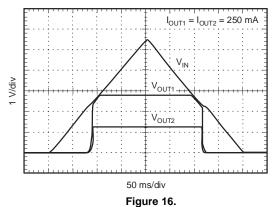


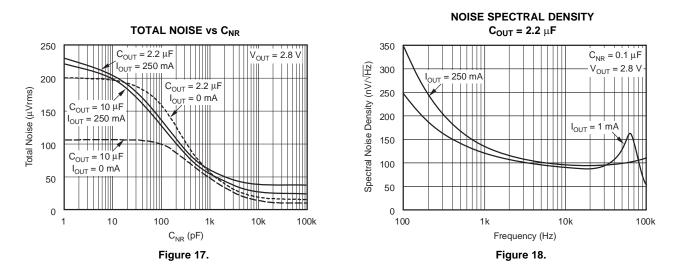


CHANNEL-TO-CHANNEL ISOLATION vs FREQUENCY 60 50 Channel Isolation (dB) 40 30 20 $C_{OUT1} = C_{OUT2} = 10 \ \mu F$ 10 $I_{OUT1} = 0$ mA to 500 mA Sinusoidal Load $I_{OUT2} = 25 \text{ mA}$ 0 0.1 1 10 100 1k Frequency (Hz) Figure 14.

TPS71256

TPS71229 POWER-UP/POWER-DOWN





Copyright © 2004–2010, Texas Instruments Incorporated

Submit Documentation Feedback

Product Folder Link(s): TPS71202 TPS71219 TPS71229 TPS71247 TPS71256 TPS71257

7

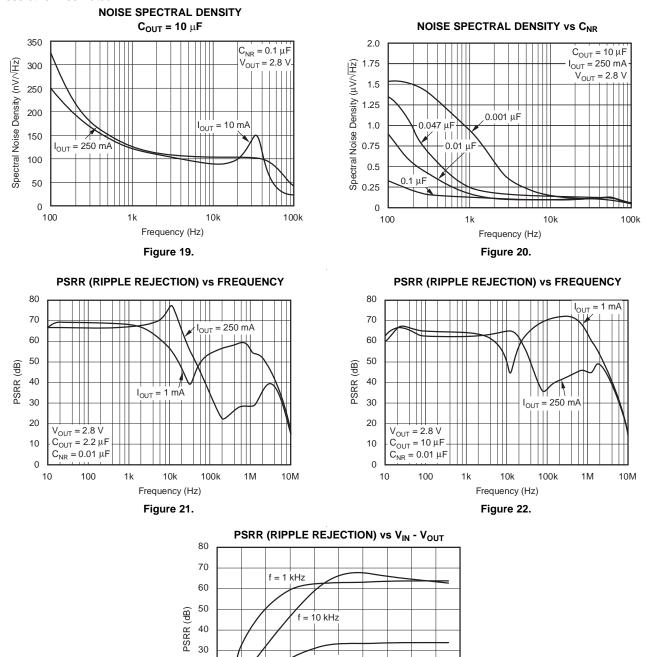




www.ti.com

TYPICAL CHARACTERISTICS (continued)

For all voltage versions at $T_J = 25^{\circ}$ C, $V_{IN} = V_{OUT(nom)} + 1$ V, $I_{OUT} = 1$ mA, $V_{EN} = 1.2$ V, $C_{OUT} = 2.2$ μ F, and $C_{NR} = 0.01$ μ F, unless otherwise noted.



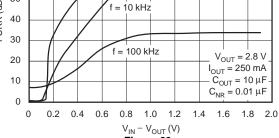


Figure 23.

8

Product Folder Link(s): TPS71202 TPS71219 TPS71229 TPS71247 TPS71256 TPS71257



www.ti.com

APPLICATION INFORMATION

The TPS712xx family of dual low-dropout (LDO) regulators has been optimized for use in noise-sensitive battery-operated equipment. The device features extremely low dropout, high PSRR, ultralow output noise, and low quiescent current (190 μ A typical per channel). When both outputs are disabled, the supply currents are reduced to less than 2 μ A. A typical application circuit is shown in Figure 24.

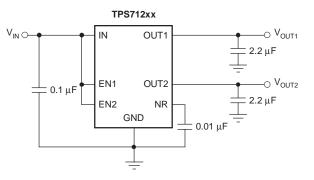


Figure 24. Typical Application Circuit (fixed-voltage versions)

INPUT AND OUTPUT CAPACITOR REQUIREMENTS

A 0.1 μ F or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS712xx, is required for stability. It improves transient response, noise rejection, and ripple rejection. A higher-value input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

The TPS712xx requires an output capacitor connected between the outputs and GND to stabilize the internal control loops. The minimum recommended output capacitor is 2.2 μ F. If an output voltage of

1.8 V or less is chosen, the minimum recommended output capacitor is 4.7 μ F. Any ceramic capacitor that meets the minimum output capacitor requirements is suitable. Capacitors with higher ESR may be used, provided the ESR is less than 1 Ω .

OUTPUT NOISE

The internal voltage reference is a key source of noise in an LDO regulator. The TPS712xx has an NR pin that is connected to the voltage reference through a 250 k Ω internal resistor. The 250 k Ω internal resistor, in conjunction with an external ceramic bypass capacitor connected to the NR pin, creates a low-pass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. To achieve a fast startup, the 250 k Ω internal resistor is shorted for 400 μ s after the device is enabled.

Because the primary noise source is the internal voltage reference, the output noise will be greater for higher output voltage versions. For the case where no noise reduction capacitor is used, the typical noise (μ Vrms) over 10 Hz to 100 kHz is 80 times the output voltage. If a 0.01 μ F capacitor is used from the NR pin to ground, the noise (μ Vrms) drops to 11.8 times the output voltage. For example, the TPS71256 exhibits only 33 μ Vrms of output voltage noise using a 0.01 μ F ceramic bypass capacitor and a 2.2 μ F ceramic output capacitor.

STARTUP CHARACTERISITCS

To minimize startup overshoot, the TPS712xx will initially target an output voltage that is approximately 80% of the final value. To avoid a delayed startup time, noise reduction capacitors of 0.01 μ F or less are recommended. Larger noise reduction capacitors will cause the output to hold at 80% until the voltage on the noise reduction capacitor exceeds 80% of the bandgap voltage. The typical startup time with a 0.001 μ F noise reduction capacitor is 60 μ s. Once one of the output voltages is present, the startup time of the other output will not be affected by the noise reduction capacitor.

9

SBVS049D - MAY 2004 - REVISED AUGUST 2010

PROGRAMMING THE TPS71202 ADJUSTABLE LDO REGULATOR

The output voltage of the TPS71202 dual adjustable regulator is programmed using an external resistor divider, as shown in Figure 25. The output voltage is calculated using Equation 1:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right)$$
(1)

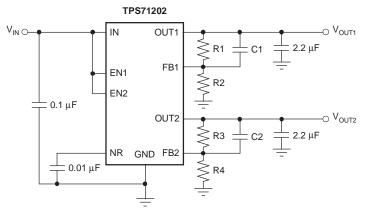
where $V_{REF} = 1.225$ V (the internal reference voltage).

Resistors R2 and R4 should be chosen for approximately a 40 μ A divider current. Lower value resistors can be used for improved noise performance, but will consume more power. Higher values should be avoided because leakage current at FB increases the output voltage error. The recommended design procedure is to choose R2 = 30.1 k Ω to set the divider current at 40 μ A, and then calculate R1 using Equation 2:

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R2$$
(2)

To improve the stability and noise performance of the adjustable version, a small compensation capacitor can be placed between OUT and FB.

For voltages \leq 1.8 V, the value of this capacitor should be 100 pF. For voltages > 1.8 V, the approximate value of this capacitor can be calculated as Equation 3:



 $C1 = \frac{(3 \times 10^{5}) \times (R1 + R2)}{(R1 \times R2)} \qquad (pF)$ (3)

The suggested value of this capacitor for several resistor ratios is shown in Figure 25. If this capacitor is not used (such as in a unity-gain configuration) or if an output voltage ≤ 1.8 V is chosen, then the minimum recommended output capacitor is 4.7 μ F instead of 2.2 μ F.

DROPOUT VOLTAGE

The TPS712xx uses a PMOS pass transistor to achieve extremely low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}), the PMOS pass device is in its linear region of operation and the input-to-output resistance is the $R_{DS, ON}$ of the PMOS pass element. Dropout voltages at lower currents can be approximated by calculating the effective R_{DS. ON} of the pass element and multiplying that resistance by the load current. $R_{DS, ON}$ of the pass element can be obtained by dividing the dropout voltage by the rated output current. For the TPS71256, the R_{DS. ON} of the pass element is 84 m Ω . The dropout voltage of the TPS712xx will be less for higher output voltage versions. This is because the PMOS pass element will have lower on-resistance due to increased gate drive.

V _{OUT}	R1/R3	R2/R4	C1/C2
1.225 V	Short	Open	Open
1.5 V	7.15 kΩ	30.1 kΩ	100 pF
2.5 V	31.6 kΩ	30.1 kΩ	22 pF
3.0 V	43.2 kΩ	30.1 kΩ	15 pF
3.3 V	49.9 kΩ	30.1 kΩ	15 pF
4.75 V	86.6 kΩ	30.1 kΩ	15 pF

Output Voltage Programming Guide

Figure 25. TPS71202 Adjustable LDO Regulator Programming

www.ti.com

10



www.ti.com

TRANSIENT RESPONSE

As with any regulator, increasing the size of the output capacitor will reduce over/undershoot magnitude but increase duration of the transient response. In the adjustable version, the addition of a capacitor, C_{FB} , from the output to the feedback pin will also improve stability and transient response. The transient response of the TPS712xx is enhanced with an active pull-down that engages when the output is over-voltaged. The active pull-down decreases the output recovery time when the load is removed. Figure 13 in the *Typical Characteristics* section shows the output transient response.

SHUTDOWN

Both enable pins are active high and are compatible with standard TTL-CMOS levels. The device is only completely disabled when both EN1 and EN2 are logic low. In this state, the LDO is completely off and the ground pin current drops to approximately 100 nA. With one output disabled, the ground pin current is slightly greater than half the nominal value. When shutdown capability is not required, the enable pins should be connected to the input supply.

INTERNAL CURRENT LIMIT

The TPS712xx internal current limit helps protect the regulator during fault conditions. During current limit, the output will source a fixed amount of current that is largely independent of the output voltage.

The TPS712xx PMOS-pass transistors have a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (that is, during power-down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting may be appropriate.

THERMAL PROTECTION

Thermal protection disables both outputs when the junction temperature of either channel rises to approximately +160°C, allowing the device to cool. When the junction temperature cools to approximately +140°C, the output circuitry is again

enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This limits the dissipation of the regulator, protecting it from damage due to overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to +125°C maximum. To estimate the margin of safety in a complete design heatsink), increase (including the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least +35°C above the maximum expected ambient condition of your application. This produces a worst-case junction temperature of +125°C at the hiahest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS712xx was designed to protect against overload conditions. It was not intended to replace proper heatsinking. Continuously running the TPS712xx into thermal shutdown will degrade device reliability.

POWER DISSIPATION

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for a JEDEC high-K board is shown in the Dissipation Ratings table. Using heavier copper will increase the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers will also improve the heat-sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass element (V_{IN} to V_{OUT}):

$$\mathsf{P}_{\mathsf{D}} = (\mathsf{V}_{\mathsf{IN}} - \mathsf{V}_{\mathsf{OUT}}) \times \mathsf{I}_{\mathsf{OUT}} \tag{4}$$

Power dissipation can be minimized by using the lowest possible input voltage necessary to assure the required output voltage.

SBVS049D - MAY 2004 - REVISED AUGUST 2010



www.ti.com

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Cł	hanges from Revision C (July, 2005) to Revision D	Page
•	Replaced the Dissipation Ratings table with the Thermal Information table	3



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS71202DRCR	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARQ	Samples
TPS71202DRCRG4	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARQ	Samples
TPS71202DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARQ	Samples
TPS71202DRCTG4	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARQ	Samples
TPS71219DRCR	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARW	Samples
TPS71219DRCRG4	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARW	Samples
TPS71219DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARW	Samples
TPS71229DRCR	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARU	Samples
TPS71229DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARU	Samples
TPS71229DRCTG4	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARU	Samples
TPS71247DRCR	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARS	Samples
TPS71247DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARS	Samples
TPS71256DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARV	Samples
TPS71256DRCTG4	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ARV	Samples
TPS71257DRCR	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ART	Samples
TPS71257DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ART	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. **PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



www.ti.com

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nomina												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS71202DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71202DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71219DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71219DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71229DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71229DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71247DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71247DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71256DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71257DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS71257DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

Texas Instruments

www.ti.com

PACKAGE MATERIALS INFORMATION

16-Oct-2020



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS71202DRCR	VSON	DRC	10	3000	853.0	449.0	35.0
TPS71202DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS71219DRCR	VSON	DRC	10	3000	853.0	449.0	35.0
TPS71219DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS71229DRCR	VSON	DRC	10	3000	853.0	449.0	35.0
TPS71229DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS71247DRCR	VSON	DRC	10	3000	853.0	449.0	35.0
TPS71247DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS71256DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS71257DRCR	VSON	DRC	10	3000	853.0	449.0	35.0
TPS71257DRCT	VSON	DRC	10	250	210.0	185.0	35.0

DRC 10

3 x 3, 0.5 mm pitch

GENERIC PACKAGE VIEW

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





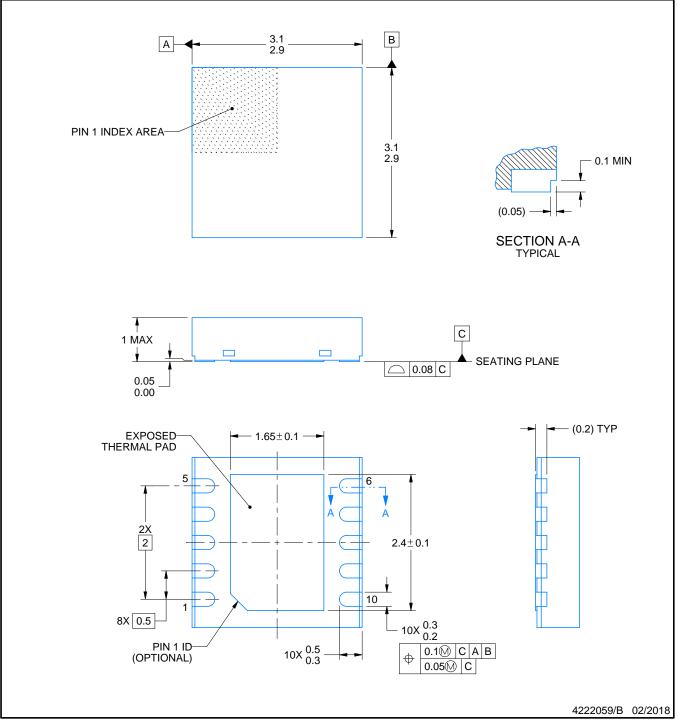
DRC0010K



PACKAGE OUTLINE

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

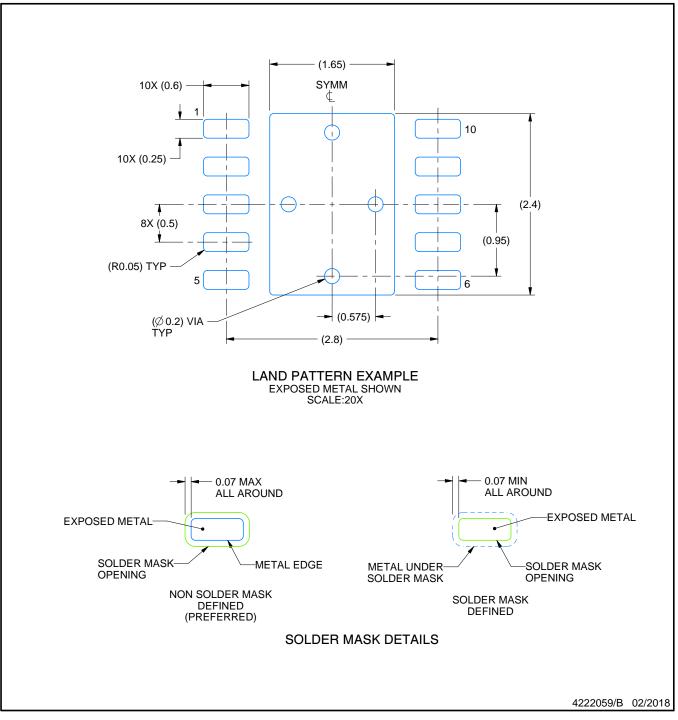


DRC0010K

EXAMPLE BOARD LAYOUT

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

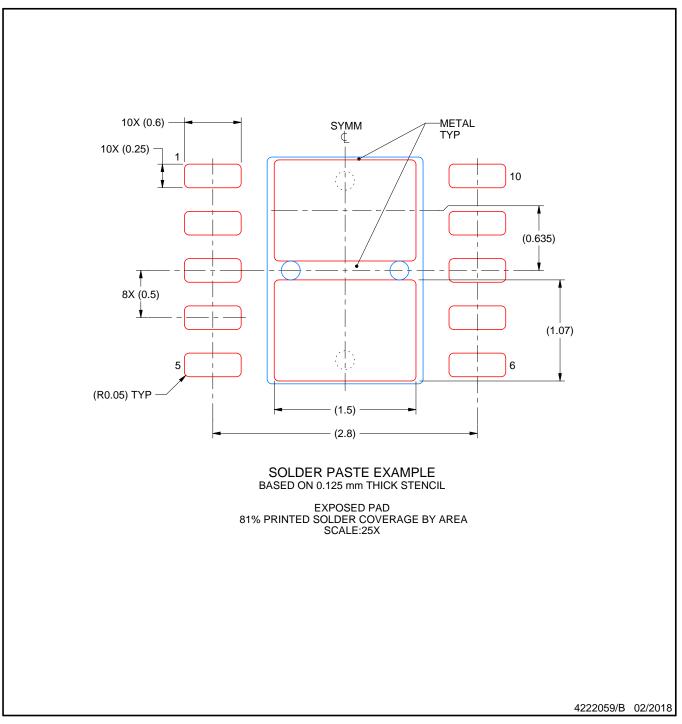


DRC0010K

EXAMPLE STENCIL DESIGN

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (https://www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021, Texas Instruments Incorporated